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Front Matter: Volume 10725

, "Front Matter: Volume 10725," Proc. SPIE 10725, Low-Dimensional Materials and Devices 2018, 1072501 (15 October 2018); doi: 10.1117/12.2516176

Event: SPIE Nanoscience + Engineering, 2018, San Diego, California, United States

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Low-Dimensional Materials and Devices 2018

Nobuhiko P. Kobayashi
A. Alec Talin
M. Saif Islam
Albert V. Davydov
Editors

22–23 August 2018
San Diego, California, United States

Sponsored and Published by
SPIE

Volume 10725

Proceedings of SPIE 0277-786X, V. 10725

SPIE is an international society advancing an interdisciplinary approach to the science and application of light.

Low-Dimensional Materials and Devices 2018, edited by Nobuhiko P. Kobayashi, A. Alec Talin,
M. Saif Islam, Albert V. Davydov, Proc. of SPIE Vol. 10725, 1072501 · © 2018 SPIE
CCC code: 0277-786X/18/\$18 · doi: 10.1117/12.2516176

Proc. of SPIE Vol. 10725 1072501-1

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Author(s), "Title of Paper," in *Low-Dimensional Materials and Devices 2018*, edited by Nobuhiko P. Kobayashi, A. Alec Talin, M. Saif Islam, Albert V. Davydov, Proceedings of SPIE Vol. 10725 (SPIE, Bellingham, WA, 2018) Seven-digit Article CID Number.

ISSN: 0277-786X
ISSN: 1996-756X (electronic)

ISBN: 9781510620216
ISBN: 9781510620223 (electronic)

Published by

SPIE

P.O. Box 10, Bellingham, Washington 98227-0010 USA
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